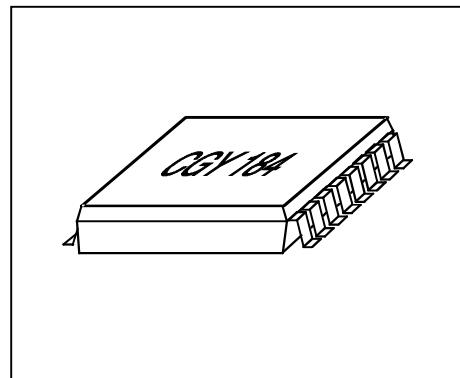


**GaAs MMIC****Preliminary Data**

- Power amplifier for PCN applications
- 2.5 W (34dBm) output power at 3.5 V
- Overall power added efficiency 43 %
- Fully integrated 4 stage amplifier
- Power ramp control
- Input matched to 50 ohms, simple output match

ESD: Electrostatic discharge sensitive device,  
observe handling precautions!



Type	Marking	Ordering code (taped)	Package <sup>1)</sup>
CGY 184	CGY 184	Q62702G62	MW 16

**Maximum ratings**

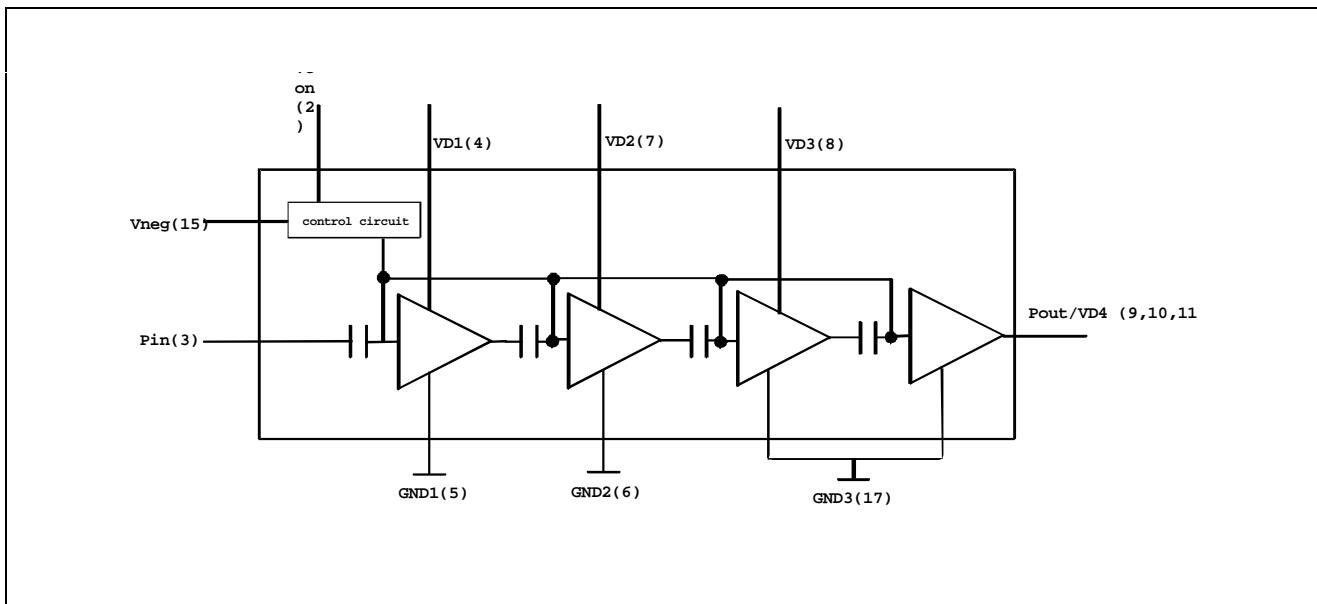
Characteristics	Symbol	max. Value	Unit
Positive supply voltage	$V_D$	9	V
Supply current	$I_D$	4	A
Channel temperature	$T_{Ch}$	150	°C
Storage temperature	$T_{stg}$	-55...+150	°C
Pulse peak power dissipation duty cycle 12.5%, ton=0.577ms	$P_{Pulse}$	tbd	W
Total power dissipation ( $T_c \leq 82$ °C) $T_c$ : Temperature on case	$P_{tot}$	8.5	W

**Thermal Resistance**

Characteristics	Symbol	max. Value	Unit
Junction-Case <sup>2)</sup>	$R_{thJC}$	$\leq 8.5$	K/W

<sup>1)</sup> Dimensions see page 14

<sup>2)</sup> see also page 9

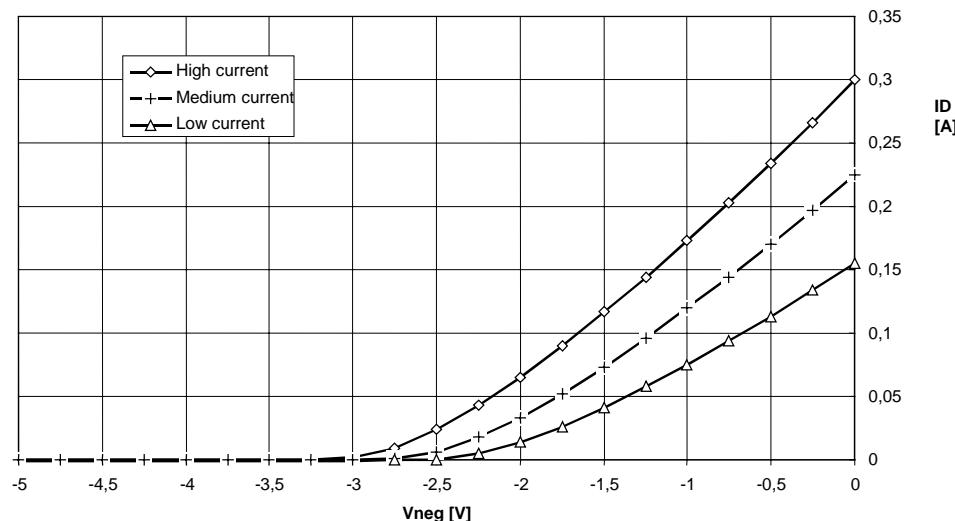
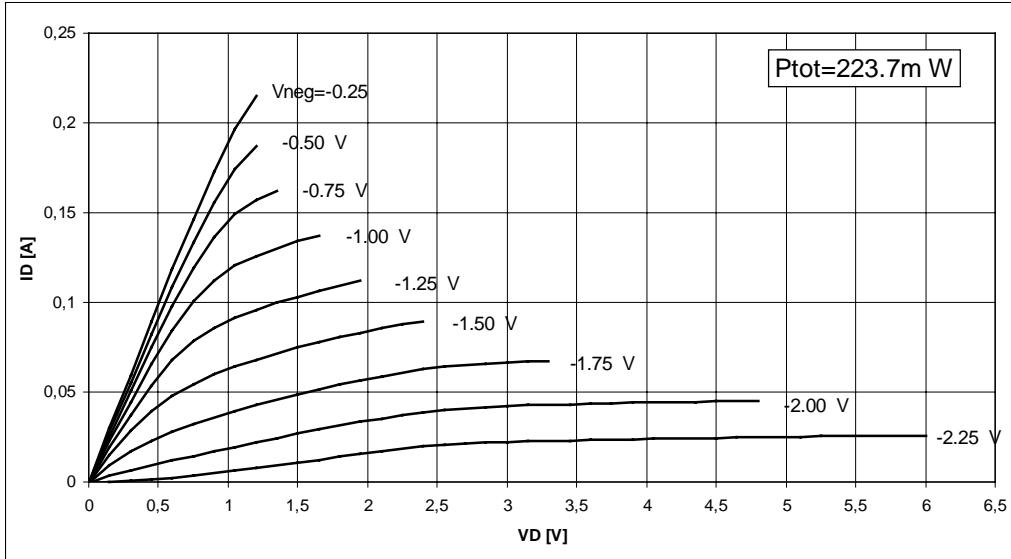
**Functional block diagram**

Pin #		Configuration
1	n. c.	
2	Vcon	Control voltage for power ramping
3	P <sub>IN</sub>	RF-input
4	V <sub>D1</sub>	Drain voltage 1st stage
5	Gnd1	Ground pin 1st stage
6	Gnd2	Ground pin 2nd stage
7	V <sub>D2</sub>	Drain voltage 2nd stage
8	V <sub>D3</sub>	Drain voltage 3rd stage
9,10,11	P <sub>OUT</sub> /V <sub>D4</sub>	Drain voltage 4th stage and RF-output
12	n. c.	
13	n. c.	
14	n. c.	
15	V <sub>neg</sub>	Block capacitor negativ voltage generator
16	n. c.	
(17)	GND3	Ground (backside of MW16 housing)

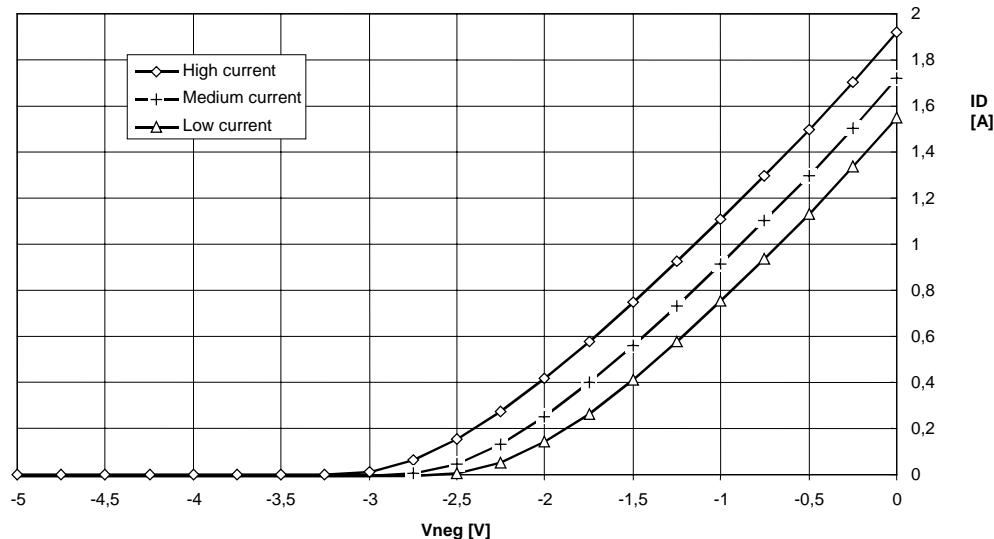
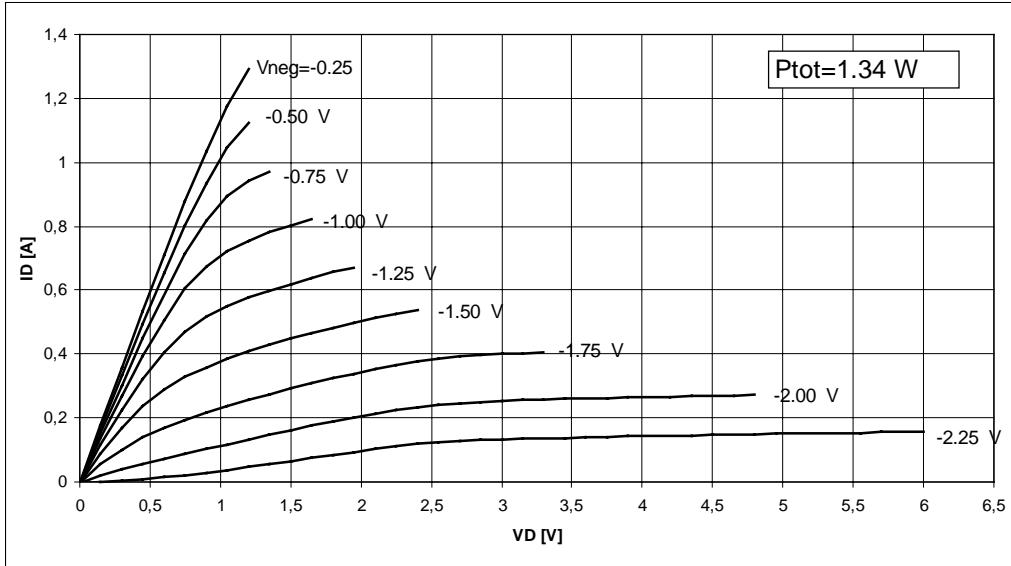
**Electrical characteristics**

( $T_A = 25^\circ\text{C}$ ,  $f=1.75 \text{ GHz}$ ,  $Z_S=Z_L=50 \text{ Ohm}$ ,  $V_D=3.5V$ ,  $V_{aux}=3.5V$ ,  $V_{control}=2.5V$ , unless otherwise specified; pulsed with a duty cycle of 12.5%,  $t_{on}=577\text{usec}$ )

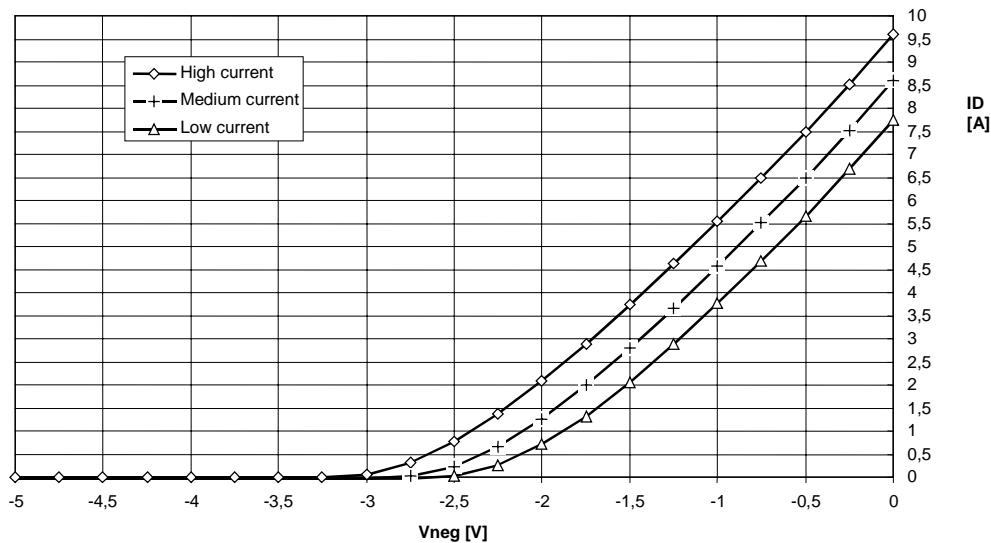
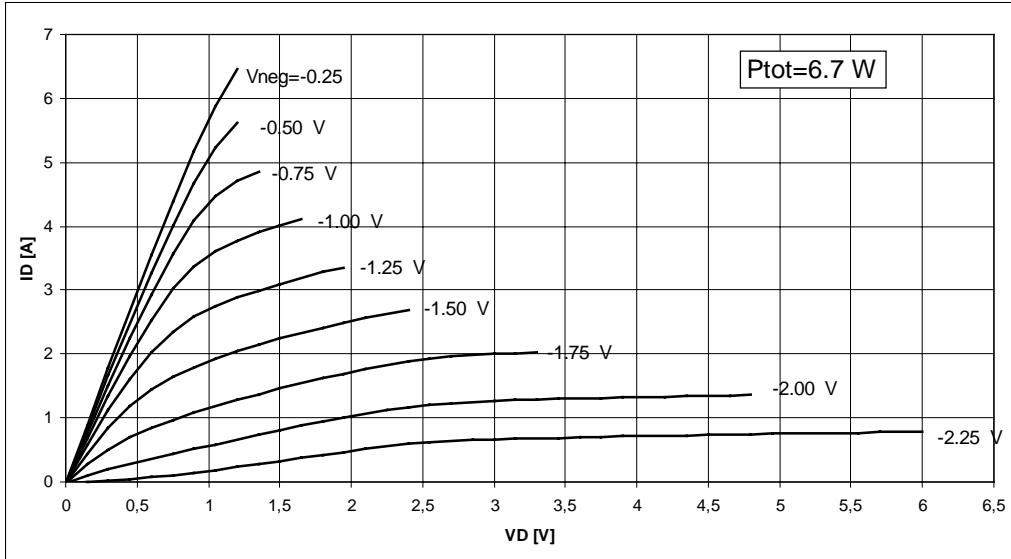
<b>Characteristics</b>	<b>Symbol</b>	<b>min</b>	<b>typ</b>	<b>max</b>	<b>Unit</b>
Supply current $V_D=3.5V$ ; $P_{in}=0dBm$	$I_{DD}$	-	1.67	-	A
Supply current neg. voltage gener. $V_{aux}=3.5V$	$I_{aux}$	-	10	-	mA
Control Current	$I_C$		2	3	mA
Shut-off current ( $V_C=0V$ , $V_D=3.5V$ , no RF- drive )	$I_D$		40		$\mu\text{A}$
Small signal gain $P_{in} = -10dBm$	$G$	-	40	-	dB
Power gain $V_D=3.5V$ ; $P_{in}=0dBm$	$G$	-	34	-	dB
Output Power $V_D=3.5V$ ; $P_{in}=0dBm$	$P_o$	-	34	-	dBm
Power gain $V_D=3.5V$ ; $P_{in}=0dBm$ , $T=85^\circ\text{C}$	$G$	-	33.7	-	dB
Output Power $V_D=3.5V$ ; $P_{in}=0dBm$ , $T=85^\circ\text{C}$	$P_o$	-	33.7	-	dBm
Overall Power added Efficiency $V_D=3.5V$ ; ; $V_C=2.5V$ ; $P_{in}=0dBm$	□	-	43	-	%
Dynamic range ( $P_{out,max}-P_{out,min}$ ) $V_C= 0.5....2.5V$		-	80	-	dB
Harmonics $V_C=2.2V$ , $P_{in}=0dBm$	$2f_0$ $3f_0$	- -	-60 -40	-	dBc
RX-Noise Power $V_C=2.2V$ ; $P_{in}=0dBm$ ; $f_{RX}=1.805....1.88GHz$		-	-80	-	dBm/ 100kHz
Input VSWR $V_D=3.5V$	-	-	1.8 : 1	-	-

**DC-ID(V<sub>neg</sub>) characteristics – typical values of stage 1 and 2, V<sub>D</sub>=3V****DC-Output characteristics – typical values of stage 1 and 2**

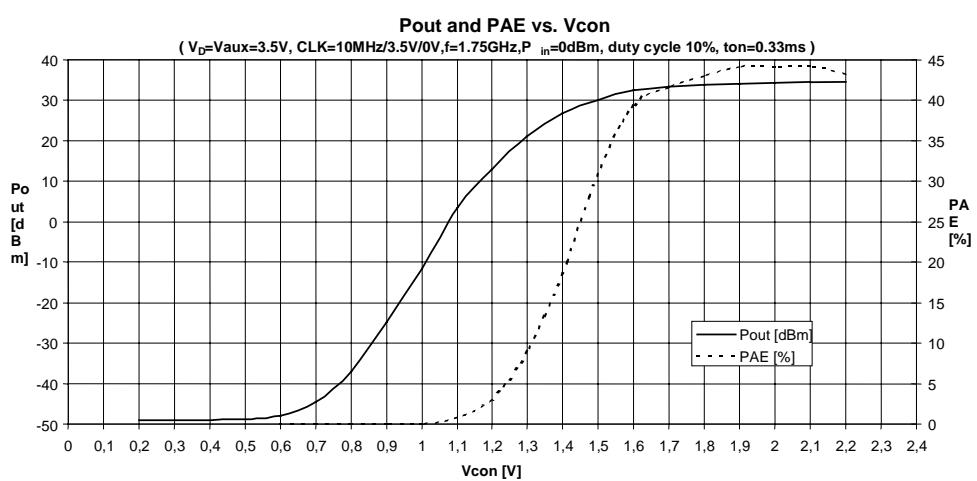
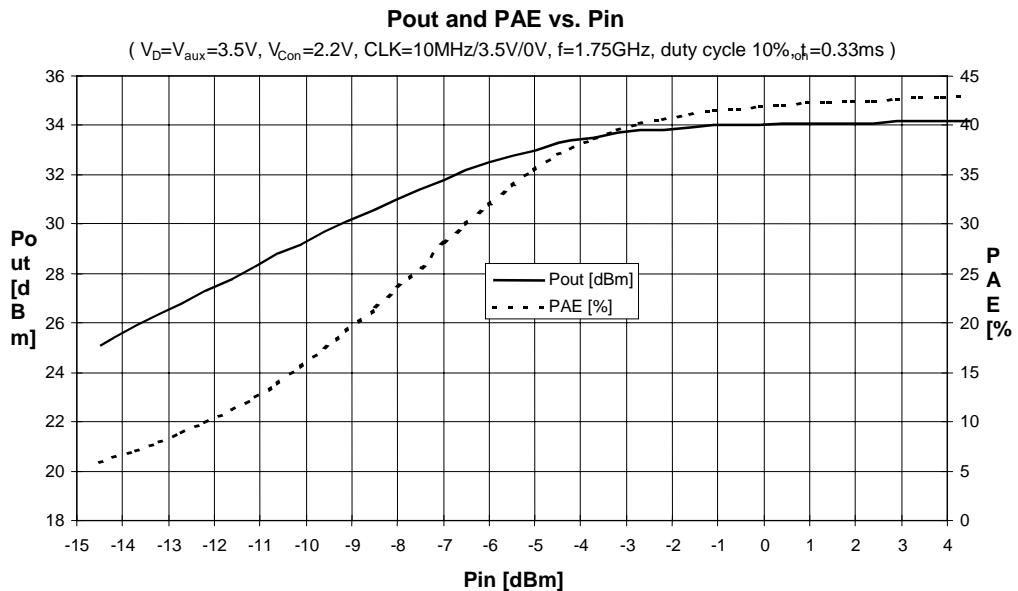
Pin 2( V<sub>con</sub> ) has to be open during measuring DC-characteristics

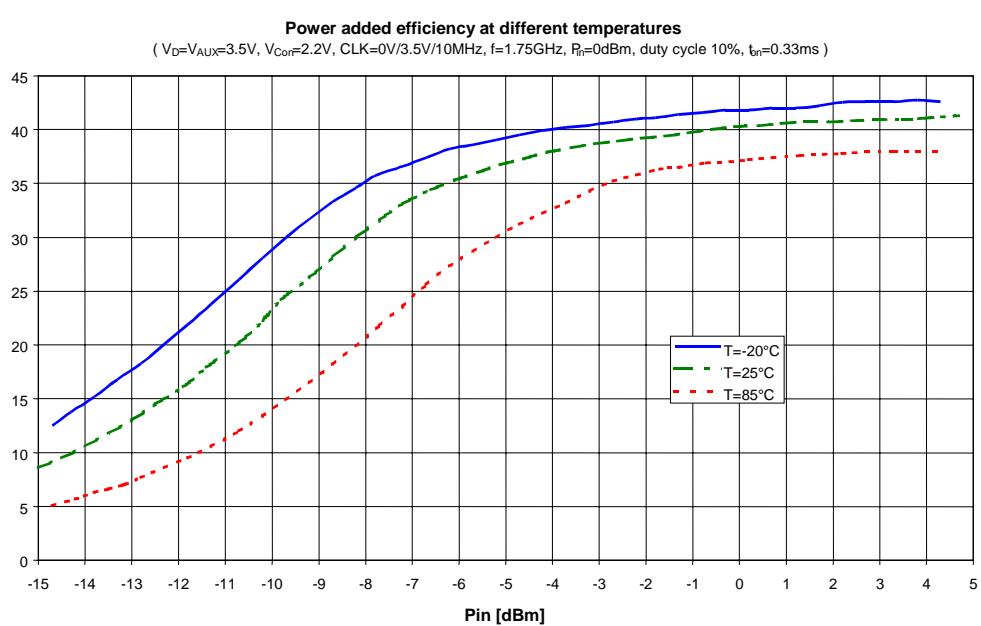
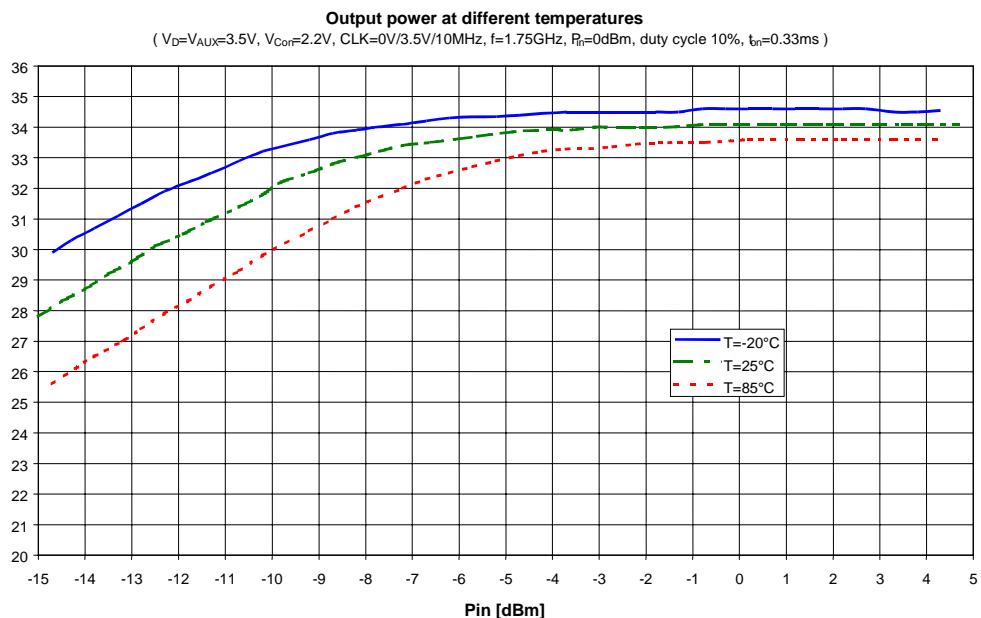
**DC-ID(V<sub>neg</sub>) characteristics – typical values of stage 3, VD=3V****DC-Output characteristics – typical values of stage 3**

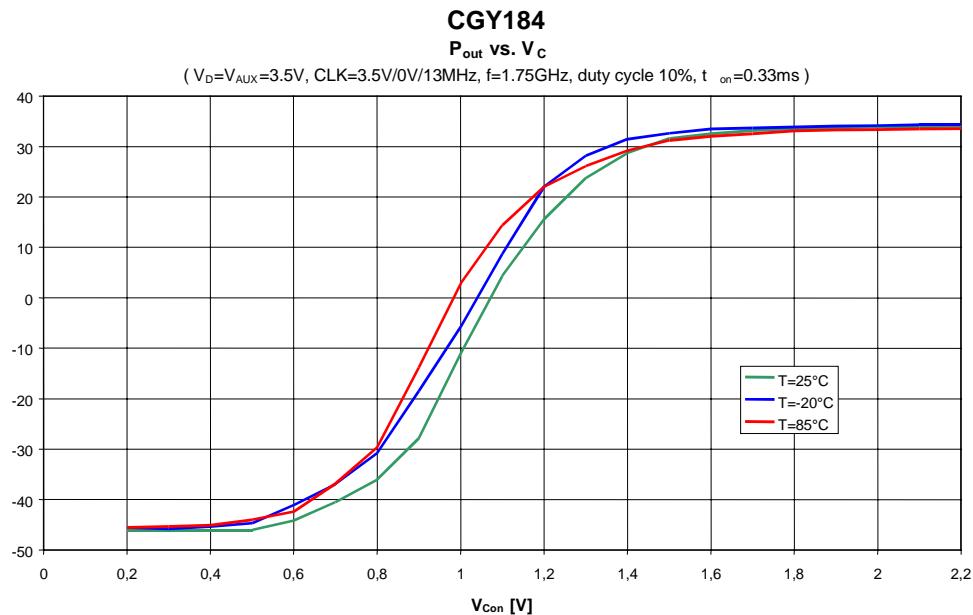
Pin 2( Vcon ) has to be open during measuring DC-characteristics

**DC-ID(V<sub>neg</sub>) characteristics – typical values of stage 4, VD=3V****DC-Output characteristics – typical values of stage 4**

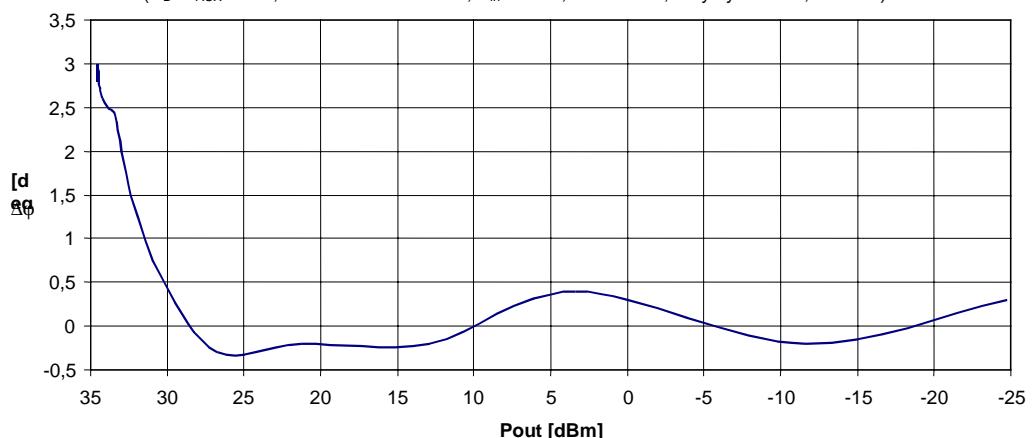
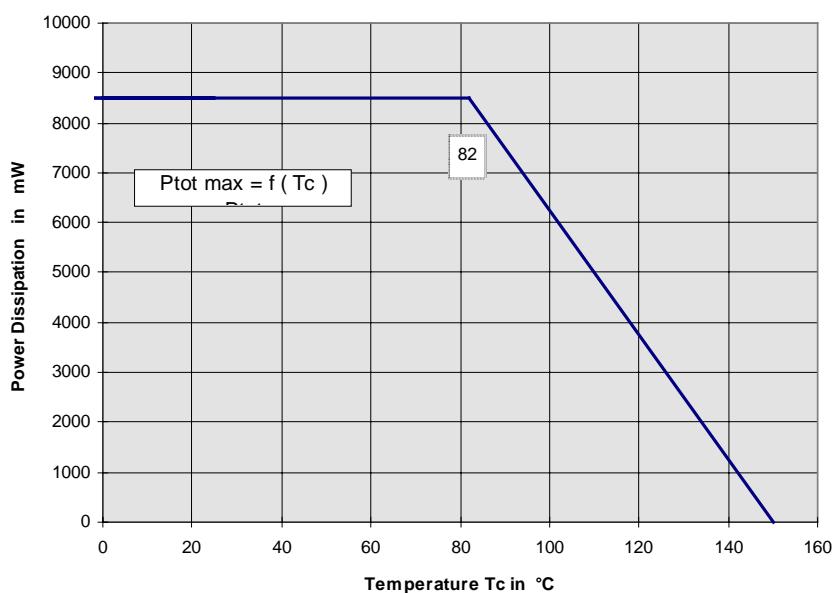
Pin 2( V<sub>con</sub> ) has to be open during measuring DC-characteristics





**AM – PM Conversion:**( Conditions: V<sub>D</sub>=V<sub>AUX</sub>=3.5V, f=1.75GHz, CLK=10MHz/3.5V/0V, P<sub>out</sub> controlled by V<sub>Con</sub> )

V <sub>Con</sub> [V]	Δφ [deg/dB]	P <sub>out</sub> [dBm]
2,2	2,8	34,53
2,1	3	34,53
2	2,7	34,37
1,9	2,6	34,2
1,8	2,5	33,87
1,7	2,4	33,37
1,6	1,5	32,37
1,5	0,5	30,2
1,4	-0,3	26,7
1,3	-0,2	21,2
1,2	-0,2	12,87
1,1	0,4	3,37
1	-0,2	-11,63
0,9	0,3	-24,8

**AM - PM - conversion** $\Delta\phi$  vs. Pout(V<sub>D</sub>=V<sub>AUX</sub>=3.5V, CLK=10MHz/3.5V/0V, P<sub>in</sub>=0dBm, f=1.75GHz, duty cycle 10%, T=25°C)**Ptotmax in mW**

**Thermal Resistance and Temperature Considerations:**

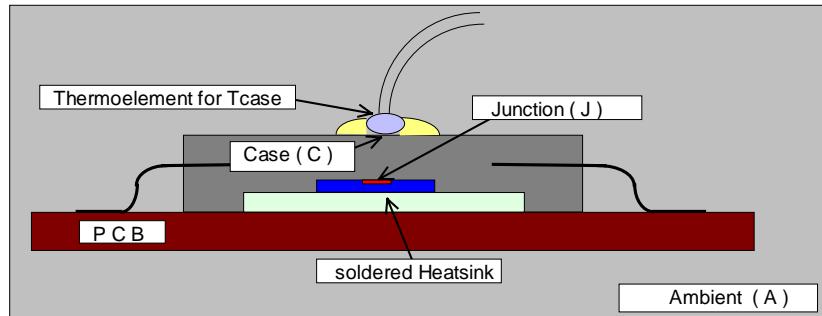
Because the MW16 heat sink is not easily accessible to a temperature measurement the thermal resistance is defined as  $R_{thJC}$  using the case temperature  $T_C$

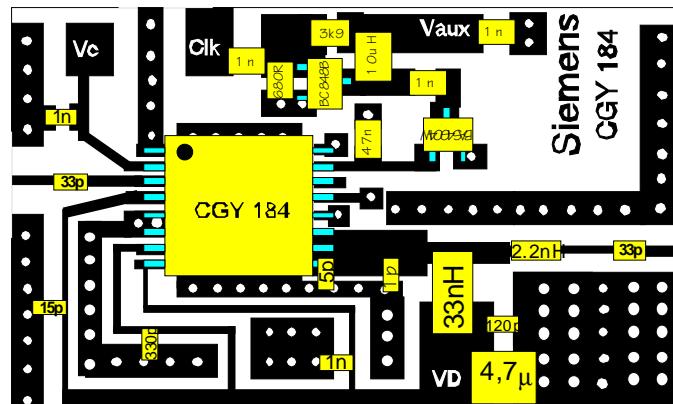
- Calculation of Junction Temperature  $T_J$  :

$$T_J = T_C + R_{thJC} * P_{tot}$$

- Measurement of Case Temperature  $T_C$  :

$T_C$  should be measured in operation at the upper side of the case where the temperature is highest. Small thermoelements  $\leq 1\text{mm}$  (thin wires, thermopaste) and thermopapers with low heat dissipation are well suited.



**CGY184 application board:**

Layout size is 32mm x 19mm

**Connections:**

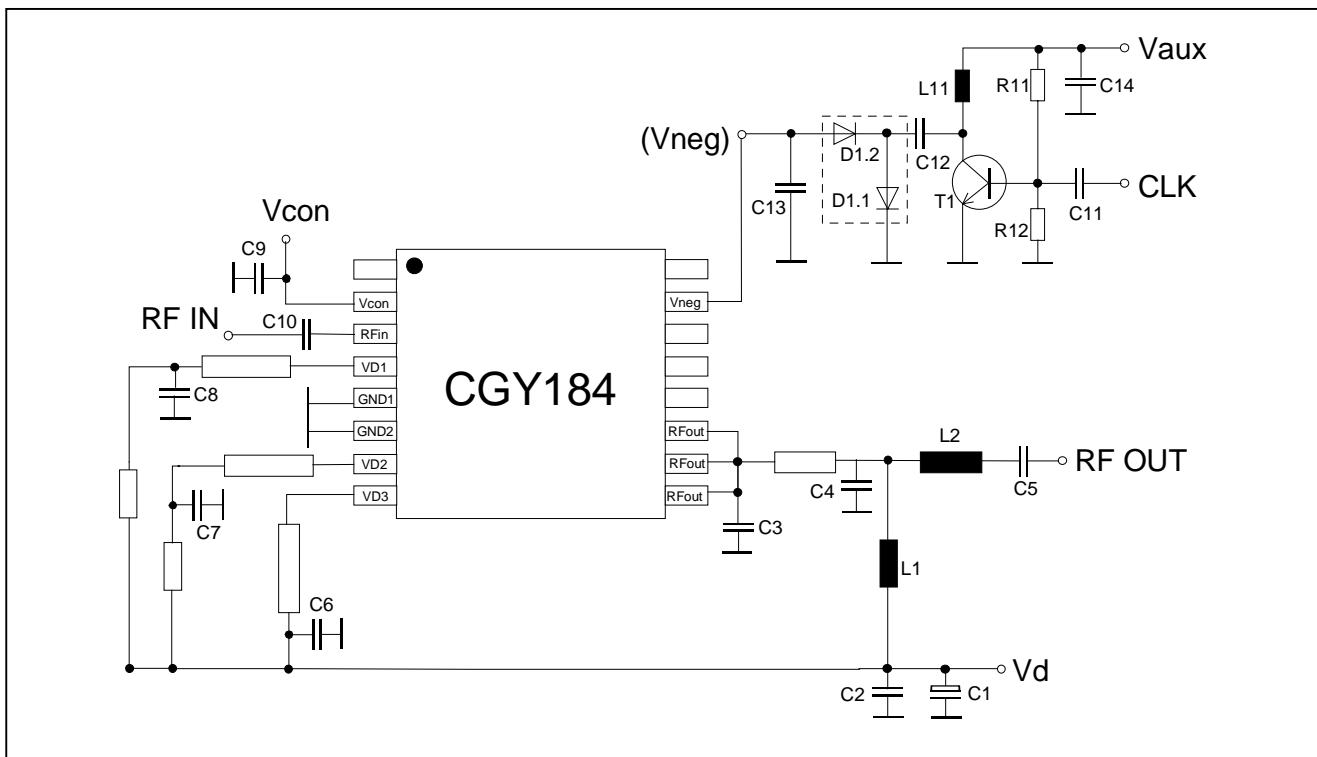
- Vd 2.7 to 6VDC, pulsed (PCN: 12,5% duty cycle, ton=0.577ms)
- Vaux 2.7 to 6VDC
- Vcontrol 0.2 to 2.2VDC (0.2V: min Pout, 2.2V: max Pout)
- CLK 5 MHz to 15 MHz (with a 10uH inductor)  
or 150 kHz to 250 kHz (with a 100uH inductor instead of the 10uH)  
(rectangular signal, 50% duty, 0 Volt to Vd voltage level)

**Power on sequence:**

1. continuous clock (CLK) on
2. turn on Vaux ==> check negative voltage at pin#16 (-4.....-10V)
3. turn on Vcon (may be at the same time as 2)  
turn on Drainvoltage Vd  
turn on Input Power

**Operation without using the negative voltage generator:**

If you don't want to use the internal negative voltage generator, you can also apply -4....-6 V at pin#15 (Vneg-Pin). In this case the passive devices at the pins 1, 14 and 16 are not necessary (1 inductor and 3 capacitors).

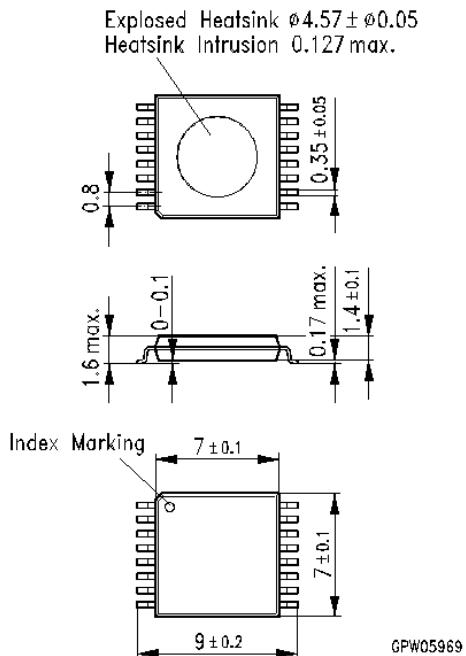
**Part List:**

CGY184		Negative Voltage Generator	
L1	33nH*	D1	BAS40-04W
L2	2.2nH**	T1	BC848B
C1	4.7μF	L11	10uH***
C2	120pF	C11	1nF
C3	5pF	C12	1nF
C4	1pF	C13	47nF
C5	33pF	C14	1nF
C6	1nF	R11	3.8kOhm
C7	330pF	R12	680Ohm
C8	15pF		
C9	1nF		
C10	33pF		

\* 33nH SMD-Inductor for drain3: Part Number BV1250 distribution by  
*Horst David GmbH, 85375 Neufarn, Germany*  
*Phone-No ..8165/9548-0 , Fax-No ..8165/9548-28*

\*\* Toko Type LL1608-FH Chip Induktor

\*\*\* Chip-Induktor Simid02  
(Siemens-Matsushita Ordering-Code: B82422-A1103-K100 )

**Semiconductor Device Outline MW16**

Published by Siemens AG, Bereich Bauelemente, Vertrieb, Produkt-Information,  
Balanstraße 73, D-81541 München

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